US-PAT-NO: 5653892

DOCUMENT-IDENTIFIER: US 5653892 A

TITLE: Etching of ceramic materials with an

elevated thin film

----- KWIC -----

Detailed Description Text - DETX (7):

In FIG. 1 a photoresist layer 36 has been patterned by conventional

photolithography over an organic layer 38 which covers the BST substrate 40.

Organic layer $38\ \mathrm{may}\ \mathrm{be}\ \mathrm{any}\ \mathrm{easily}\ \mathrm{removed}\ \mathrm{material}\ \mathrm{having}\ \mathrm{the}\ \mathrm{desired}\ \mathrm{physical}$

characteristics such as **Polyimide Release Layer**, "PIRL", a trademark of Brewer

Science, Inc., or **photoresist**. Layer 38 is patterned into a grid over the

points on the substrate 40 which will become thermal isolation trenches as

shown in FIG. 2. Layer 38 may itself be photodefineable, or it may be

patterned using a separate mask layer.

US-PAT-NO: 5607600

DOCUMENT-IDENTIFIER: US 5607600 A

TITLE: Optical coat reticulation post

hybridization

----- KWIC -----

Detailed Description Text - DETX (11):

A second embodiment of the present invention is shown in FIGS. 5-7. A

protective material 64 may be, for example, spun onto the surface of the

integrated circuit sensing circuit 48 prior to bonding infrared sensing array

46 and sensing integrated circuit structure 48 together, as shown in FIG. 5.

The protective material 64 is preferably an organic coating comprising

photoresist and PIRL (polyimide release layer). After the thermal isolation

slots 62 have been etched, the protective material 64 may be removed, for

example, as a gas by ashing in a plasma reactor. Preferably, the protective

material 64 is removed entirely, as shown in FIG. 6.

US-PAT-NO: 6307721

DOCUMENT-IDENTIFIER: US 6307721 B1

TITLE: Thin read gap magnetoresistive (MR)

sensor element and

method for fabrication thereof

----- KWIC -----

Detailed Description Text - DETX (11):

There is also shown in FIG. 1 the presence of a first lift off stencil 16

formed upon the patterned first magnetoresistive (MR) layer 14. The first lift

off stencil 16 comprises a patterned first release layer 16a formed upon the

patterned first magnetoresistive (MR) layer 14 and a patterned first

photoresist layer 16b formed symmetrically overhanging the patterned first

release layer 16a. While any of several release materials may be employed in

forming the patterned first release layer 16a, including but not limited to

organic polymer release materials such as but not limited to polysulfone

organic polymer release materials and polyimide organic polymer release

materials, for the preferred embodiments of the present invention the patterned

first release layer 16a is preferably formed of a PMGI organic polymer release

material which is an organic polymer **photoresist** material. Preferably, the

patterned first release layer 16a is formed to a thickness of from about 500 to

about 10000 angstroms upon the patterned first magnetoresistive (MR) layer 14.

Similarly, although any of several photoresist materials may be employed for

forming the patterned first photoresist layer 16b, including but not limited to

photoresist materials selected from the general groups of